# Low-Voltage 1.8/2.5/3.3V 16-Bit Buffer

# With 3.6 V-Tolerant Inputs and Outputs (3-State, Non-Inverting)

The 74VCXH16244 is an advanced performance, non-inverting 16-bit buffer. It is designed for very high-speed, very low-power operation in 1.8 V, 2.5 V or 3.3 V systems.

When operating at 2.5 V (or 1.8 V) the part is designed to tolerate voltages it may encounter on either inputs or outputs when interfacing to 3.3 V busses. It is guaranteed to be overvoltage tolerant to 3.6 V.

The 74VCXH16244 is nibble controlled with each nibble functioning identically, but independently. The control pins may be tied together to obtain full 16-bit operation. The 3-state outputs are controlled by an Output Enable  $(\overline{OEn})$  input for each nibble. When  $\overline{OEn}$  is LOW, the outputs are on. When  $\overline{OEn}$  is HIGH, the outputs are in the high impedance state. The data inputs include active bushold circuitry, eliminating the need for external pullup resistors to hold unused or floating inputs at a valid logic state.

#### Features

- Designed for Low Voltage Operation:  $V_{CC} = 1.65 \text{ V} 3.6 \text{ V}$
- 3.6 V Tolerant Inputs and Outputs
- High Speed Operation: 2.5 ns max for 3.0 V to 3.6 V

3.0 ns max for 2.3 V to 2.7 V

6.0 ns max for 1.65 V to 1.95 V

• Static Drive: ±24 mA Drive at 3.0 V

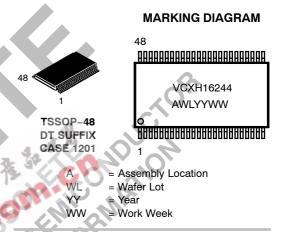
±18 mA Drive at 2.3 V ±6 mA Drive at 1.65 V

- Supports Live Insertion and Withdrawal
- Includes Active Bushold to Hold Unused or Floating Inputs at a Valid Logic State
- $I_{OFF}$  Specification Guarantees High Impedance When  $V_{CC} = 0 V^*$
- Near Zero Static Supply Current in All Three Logic States (20 μA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds ±250 mA @ 125°C
- ESD Performance: Human Body Model >2000 V Machine Model >200 V
- All Devices in Package TSSOP are Inherently Pb-Free\*\*
- \*To ensure the outputs activate in the 3-state condition, the output enable pins should be connected to  $V_{CC}$  through a pullup resistor. The value of the resistor is determined by the current sinking capability of the output connected to the  $\overline{OE}$  pin.
- \*\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



#### ON Semiconductor®

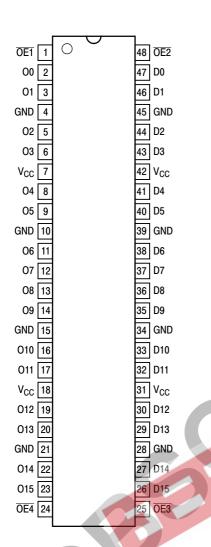
http://onsemi.com



## ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
74VCXH16244DT	TSSOP (Pb-Free)	39 / Rail
74VCXH16244DTR	TSSOP (Pb-Free)	2500 / Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.



OE1 OE3 00:3 D8:11 08:11 D0:3 D12:15 012:15 One of Four

Figure 2. Logic Diagram

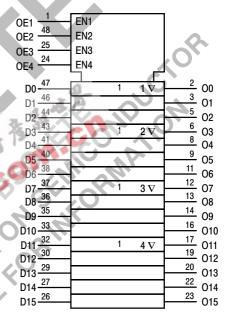


Figure 1. 48-Lead Pinout (Top View)

Figure 3. IEC Logic Diagram

28 GND 27 D14 26 D15 25 OE3 48-Lead Pinout Top View)	D7 37 1 3 N D8 36
Table 1. PIN NAMES	
Pins	Function
OEn D0-D15 O0-O15	Output Enable Inputs Inputs Outputs
<b>X</b>	

## **TRUTH TABLE**

OE1	D0:3	O0:3	OE2	D4:7	04:7	OE3	D8:11	O8:11	OE4	D12:15	O12:15
L	L	L	L	L	L	L	L	L	L	L	L
L	Н	Н	L	Н	Н	L	Н	Н	L	Н	Н
Н	Х	Z	Н	Х	Z	Н	Х	Z	Н	Х	Z

H = High Voltage Level

L = Low Voltage Level

Z = High Impedance State

X = High or Low Voltage Level and Transitions Are Acceptable, for I<sub>CC</sub> reasons, DO NOT FLOAT Inputs

#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Condition	Unit
V <sub>CC</sub>	DC Supply Voltage	−0.5 to +4.6		V
VI	DC Input Voltage	$-0.5 \le V_{I} \le +4.6$		V
Vo	DC Output Voltage	$-0.5 \le V_{O} \le +4.6$	Output in 3-State	V
		$-0.5 \le V_{O} \le V_{CC} + 0.5$	Note 1; Outputs Active	V
I <sub>IK</sub>	DC Input Diode Current	-50	V <sub>I</sub> < GND	mA
I <sub>OK</sub>	DC Output Diode Current	-50	V <sub>O</sub> < GND	mA
		+50	V <sub>O</sub> > V <sub>CC</sub>	mA
I <sub>O</sub>	DC Output Source/Sink Current	±50		mA
I <sub>CC</sub>	DC Supply Current Per Supply Pin	±100		mA
I <sub>GND</sub>	DC Ground Current Per Ground Pin	±100		mA
T <sub>STG</sub>	Storage Temperature Range	-65 to +150		°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

#### RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	479	Min	Тур	Max	Unit
V <sub>CC</sub>	Supply Voltage	Operating Data Retention Only	1.65 1.2	3.3 3.3	3.6 3.6	V
VI	Input Voltage	A C	-0.3		3.6	V
V <sub>O</sub>	Output Voltage	(Active State) (3-State)	0		V <sub>CC</sub> 3.6	V
I <sub>OH</sub>	HIGH Level Output Current, V <sub>CC</sub> = 3.0 V - 3.6 V	V .Q .Q			-24	mA
I <sub>OL</sub>	LOW Level Output Current, V <sub>CC</sub> = 3.0 V – 3.6 V	<u>70, °0</u>			24	mA
I <sub>OH</sub>	HIGH Level Output Current, V <sub>CC</sub> = 2.3 V - 2.7 V			-18	mA	
l <sub>OL</sub>	LOW Level Output Current, V <sub>CC</sub> = 2.3 V - 2.7 V	19			18	mA
I <sub>OH</sub>	HIGH Level Output Current, V <sub>CC</sub> = 1.65 V - 1.95 V	0			-6	mA
I <sub>OL</sub>	LOW Level Output Current, V <sub>CC</sub> = 1.65 V - 1.95 V				6	mA
T <sub>A</sub>	Operating Free-Air Temperature		-40		+85	°C
$\Delta t/\Delta V$	Input Transition Rise or Fall Rate, V <sub>IN</sub> from 0.8 V to 2.0	V, V <sub>CC</sub> = 3.0 V	0		10	ns/V
	Input Transition Rise or Fall Rate, V <sub>IN</sub> from 0.8 V to 2.0					

<sup>1.</sup> I<sub>O</sub> absolute maximum rating must be observed.

## DC ELECTRICAL CHARACTERISTICS

			$T_A = -40^\circ$	C to +85°C	
Symbol	Characteristic	Condition	Min	Max	Unit
V <sub>IH</sub>	HIGH Level Input Voltage (Note 2)	1.65 V ≤ V <sub>CC</sub> < 2.3 V	0.65 x V <sub>CC</sub>		V
		2.3 V ≤ V <sub>CC</sub> ≤ 2.7 V	1.6		
		2.7 V < V <sub>CC</sub> ≤ 3.6 V	2.0		
V <sub>IL</sub>	LOW Level Input Voltage (Note 2)	1.65 V ≤ V <sub>CC</sub> < 2.3 V		0.35 x V <sub>CC</sub>	V
		2.3 V ≤ V <sub>CC</sub> ≤ 2.7 V		0.7	
		2.7 V < V <sub>CC</sub> ≤ 3.6 V		0.8	
V <sub>OH</sub>	HIGH Level Output Voltage	1.65 V ≤ V <sub>CC</sub> ≤ 3.6 V; I <sub>OH</sub> = −100 μA	V <sub>CC</sub> - 0.2		V
		V <sub>CC</sub> = 1.65 V; I <sub>OH</sub> = -6 mA	1.25		
		$V_{CC} = 2.3 \text{ V}; I_{OH} = -6 \text{ mA}$	2.0		
		V <sub>CC</sub> = 2.3 V; I <sub>OH</sub> = -12 mA	1.8		
		V <sub>CC</sub> = 2.3 V; I <sub>OH</sub> = -18 mA	1.7	0	
		V <sub>CC</sub> = 2.7 V; I <sub>OH</sub> = -12 mA	2.2		
		V <sub>CC</sub> = 3.0 V; I <sub>OH</sub> = -18 mA	2.4		
		V <sub>CC</sub> = 3.0 V; I <sub>OH</sub> = -24 mA	2.2		
V <sub>OL</sub>	LOW Level Output Voltage	$1.65 \text{ V} \le \text{V}_{CC} \le 3.6 \text{ V}; 1_{OL} = 100 \mu\text{A}$		0.2	V
		V <sub>CC</sub> = 1.65 V; I <sub>OL</sub> = 6 mA		0.3	
		V <sub>CC</sub> = 2.3 V; I <sub>OL</sub> = 12 mA	9	0.4	
		V <sub>CC</sub> = 2.3 V; I <sub>OL</sub> = 18 mA		0.6	
		V <sub>CC</sub> = 2.7 V; l <sub>OL</sub> = 12 mA		0.4	
		V <sub>CC</sub> = 3.0 V; l <sub>OL</sub> = 18 mA	· ·	0.4	
		V <sub>CC</sub> = 3.0 V; I <sub>OL</sub> = 24 mA		0.55	
l <sub>l</sub>	Input Leakage Current	$1.65 \text{ V} \le \text{V}_{CC} \le 3.6 \text{ V}; 0 \text{ V} \le \text{V}_{I} \le 3.6 \text{ V}$		±5.0	μΑ
I <sub>I(HOLD)</sub>	Minimum Bushold Input Current	$V_{CC} = 3.0 \text{ V}, V_{IN} = 0.8 \text{ V}$	75		μ <b>A</b>
-1(ПОСБ)		V <sub>CC</sub> = 3.0 V, V <sub>IN</sub> = 2.0 V	-75		,
		V <sub>CC</sub> = 2.3 V, V <sub>IN</sub> = 0.7 V	45		
		V <sub>CC</sub> = 2.3 V, V <sub>IN</sub> = 1.6 V	-45		
		V <sub>QC</sub> = 1.65 V, V <sub>IN</sub> = 0.57 V	25		
		V <sub>CC</sub> = 1.65 V, V <sub>IN</sub> = 1.07 V	-25		
I <sub>I (OD)</sub>	Minimum Bushold Over-Drive	Vac = 3.6 V (Note 3)	450		μA
·1 (OD)	Current Needed to Change State	V <sub>CC</sub> = 3.6 V, (Note 4)	-450		pa t
	62 0	V <sub>CC</sub> = 2.7 V, (Note 3)	300		
		V <sub>CC</sub> = 2.7 V, (Note 4)	-300		
		V <sub>CC</sub> = 1.95 V, (Note 3)	200		
	Q.	V <sub>CC</sub> = 1.95 V, (Note 4)	-200		
l <sub>oz</sub>	3-State Output Current	$1.65 \text{ V} \le \text{V}_{CC} \le 3.6 \text{ V}; \text{ 0 V} \le \text{V}_{O} \le 3.6 \text{ V};$ $\text{V}_{I} = \text{V}_{IH} \text{ or V}_{IL}$		±10	μΑ
I <sub>OFF</sub>	Power-Off Leakage Current	V <sub>CC</sub> = 0 V; V <sub>I</sub> or V <sub>O</sub> = 3.6 V		10	μΑ
I <sub>CC</sub>	Quiescent Supply Current (Note 5)	1.65 V ≤ $V_{CC}$ ≤ 3.6 V; $V_{I}$ = GND or $V_{CC}$		20	μΑ
50	(1515 S)	1.65 V $\leq$ V <sub>CC</sub> $\leq$ 3.6 V; 3.6V $\leq$ V <sub>I</sub> , V <sub>O</sub> $\leq$ 3.6 V		±20	μΑ
		, = 100 = 5.5 1, 5.5 1 2 1, 10 3 5.6 1	I	1	ρω .

- These values of V<sub>I</sub> are used to test DC electrical characteristics only.
   An external driver must source at least the specified current to switch from LOW-to-HIGH.
   An external driver must source at least the specified current to switch from HIGH-to-LOW.
   Outputs disabled or 3-state only.

## AC CHARACTERISTICS (Note 6; $t_R$ = $t_F$ = 2.0 ns; $C_L$ = 30 pF; $R_L$ = 500 $\Omega$ )

					$T_A = -40^{\circ}$	°C to +85°C	;		
			V <sub>CC</sub> = 3.0	V to 3.6 V	V <sub>CC</sub> = 2.3	V to 2.7 V	V <sub>CC</sub> = 1.65	V – 1.95 V	
Symbol	Parameter	Waveform	Min	Max	Min	Max	Min	Max	Unit
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay Input-to-Output	1	0.8 0.8	2.5 2.5	1.0 1.0	3.0 3.0	1.5 1.5	6.0 6.0	ns
t <sub>PZH</sub>	Output Enable Time to High and Low Level	2	0.8 0.8	3.5 3.5	1.0 1.0	4.1 4.1	1.5 1.5	8.2 8.2	ns
t <sub>PHZ</sub>	Output Disable Time From High and Low Level	2	0.8 0.8	3.5 3.5	1.0 1.0	3.8 3.8	1.5 1.5	6.8 6.8	ns
t <sub>OSHL</sub> t <sub>OSLH</sub>	Output-to-Output Skew (Note 7)			0.5 0.5		0.5 0.5		0.75 0.75	ns

<sup>6.</sup> For  $C_L$  = 50 pF, add approximately 300 ps to the AC maximum specification.

## AC CHARACTERISTICS ( $t_R = t_F = 2.0 \text{ ns}; C_L = 50 \text{ pF}; R_L = 500 \Omega$ )

				$T_A = -40^{\circ} \text{C to } +85^{\circ} \text{C}$			
			V <sub>CC</sub> = 3.0	V to 3.6 V	V <sub>CC</sub> =	2.7 V	
Symbol	Parameter	Waveform	Min	Max	Min	Max	Unit
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay Input-to-Output	3	1.0 1.0	3.0 3.0		3.6 3.6	ns
t <sub>PZH</sub> t <sub>PZL</sub>	Output Enable Time to High and Low Level	4	1.0	4.4		5.4 5.4	ns
t <sub>PHZ</sub>	Output Disable Time From High and Low Level	4	1.0 1.0	4.1 4.1		4.6 4.6	ns
t <sub>OSHL</sub> t <sub>OSLH</sub>	Output-to-Output Skew (Note 8)		"CE IL	0.5 0.5		0.5 0.5	ns

<sup>8.</sup> Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (toSHL) or LOW-to-HIGH (toSLH); parameter guaranteed by design.

Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device.
 The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t<sub>OSHL</sub>) or LOW-to-HIGH (t<sub>OSLH</sub>); parameter guaranteed by design.

#### **DYNAMIC SWITCHING CHARACTERISTICS**

			T <sub>A</sub> = +25°C	
Symbol	Characteristic	Condition	Тур	Unit
V <sub>OLP</sub>	Dynamic LOW Peak Voltage	$V_{CC}$ = 1.8 V, $C_L$ = 30 pF, $V_{IH}$ = $V_{CC}$ , $V_{IL}$ = 0 V	0.25	V
	(Note 9)	$V_{CC} = 2.5 \text{ V}, C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0 \text{ V}$	0.6	
		$V_{CC} = 3.3 \text{ V}, C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0 \text{ V}$	0.8	
V <sub>OLV</sub>	Dynamic LOW Valley Voltage	$V_{CC}$ = 1.8 V, $C_L$ = 30 pF, $V_{IH}$ = $V_{CC}$ , $V_{IL}$ = 0 V	-0.25	V
	(Note 9)	$V_{CC}$ = 2.5 V, $C_L$ = 30 pF, $V_{IH}$ = $V_{CC}$ , $V_{IL}$ = 0 V	-0.6	
		$V_{CC}$ = 3.3 V, $C_L$ = 30 pF, $V_{IH}$ = $V_{CC}$ , $V_{IL}$ = 0 V	-0.8	
V <sub>OHV</sub>	Dynamic HIGH Valley Voltage	$V_{CC} = 1.8 \text{ V}, C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0 \text{ V}$	1.5	V
	(Note 10)	$V_{CC} = 2.5 \text{ V}, C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0 \text{ V}$	1.9	
		$V_{CC} = 3.3 \text{ V}, C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0 \text{ V}$	2.2	

<sup>9.</sup> Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

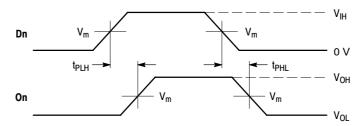
10. Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is

#### **CAPACITIVE CHARACTERISTICS**

Symbol	Parameter	Condition	Typical	Unit
C <sub>IN</sub>	Input Capacitance	Note 11	6	pF
C <sub>OUT</sub>	Output Capacitance	Note 11	7	pF
C <sub>PD</sub>	Power Dissipation Capacitance	Note 11, 10 MHz	20	pF

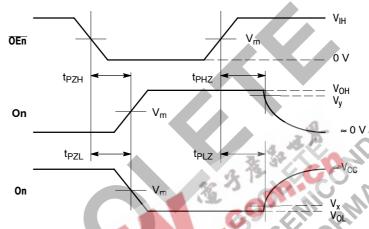
<sup>11.</sup>  $V_{CC} = 1.8 \text{ V}$ , 2.5 V or 3.3 V;  $V_{I} = 0 \text{ V or } V_{CC}$ .

measured in the HIGH state.



WAVEFORM 1 - PROPAGATION DELAYS

 $t_R$  =  $t_F$  = 2.0 ns, 10% to 90%; f = 1 MHz;  $t_W$  = 500 ns



# WAVEFORM 2 - OUTPUT ENABLE AND DISABLE TIMES

 $t_{\rm R} = t_{\rm F} = 2.0$  ns, 10% to 90%; f = 1 MHz;  $t_{\rm W} = 500$  ns

Figure 4. AC Waveforms

Table 2. AC WAVEFORMS

	V <sub>cc</sub>		
Symbol	3.3 V ± 0.3 V	2.5 V ± 0.2 V	1.8 V ± 0.15 V
V <sub>IH</sub>	2.7 V	V <sub>CC</sub>	V <sub>CC</sub>
V <sub>m</sub>	1.5 V	V <sub>CC</sub> /2	V <sub>CC</sub> /2
V <sub>x</sub>	V <sub>OL</sub> + 0.3 V	V <sub>OL</sub> + 0.15 V	V <sub>OL</sub> + 0.15 V
Vy	V <sub>OH</sub> – 0.3 V	V <sub>OH</sub> – 0.15 V	V <sub>OH</sub> – 0.15 V

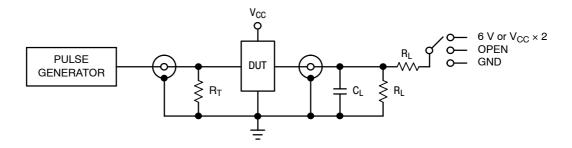
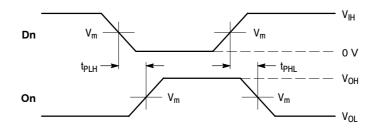


Figure 5. Test Circuit

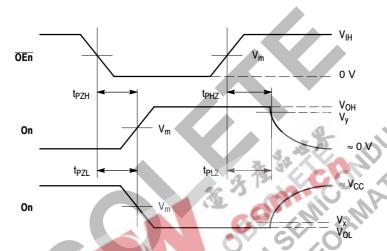
**Table 3. TEST CIRCUIT** 

Table 3. TEST CIRCUIT	
TEST	SWITCH
t <sub>PLH</sub> , t <sub>PHL</sub>	Open
t <sub>PZL</sub> , t <sub>PLZ</sub>	6 V at $V_{CC}$ = 3.3 ± 0.3 V; $V_{CC} \times$ 2 at $V_{CC}$ = 2.5 ± 0.2 V; 1.8 ± 0.15 V
t <sub>PZH</sub> , t <sub>PHZ</sub>	GND
$C_L=30$ pF or equivalent (Includes jig and $R_L=500~\Omega$ or equivalent $R_T=Z_{OUT}$ of pulse generator (typically 50	



#### **WAVEFORM 3 - PROPAGATION DELAYS**

 $t_R$  =  $t_F$  = 2.0 ns, 10% to 90%; f = 1 MHz;  $t_W$  = 500 ns



WAVEFORM 4 - OUTPUT ENABLE AND DISABLE TIMES  $t_{\rm R}$  =  $t_{\rm F}$  = 2.0 ns, 10% to 90%;  $t_{\rm F}$  = 1 MHz;  $t_{\rm W}$  = 500 ns

Figure 6. AC Waveforms

Table 4. AC WAVEFORMS

V <sub>CC</sub>						
Symbol	3.3 V ± 0.3 V	2.7 V				
V <sub>IH</sub>	2.7 V	2.7 V				
V <sub>m</sub>	1.5 V	1.5 V				
V <sub>x</sub>	V <sub>OL</sub> + 0.3 V	V <sub>OL</sub> + 0.3 V				
$V_{y}$	V <sub>OH</sub> – 0.3 V	V <sub>OH</sub> – 0.3 V				

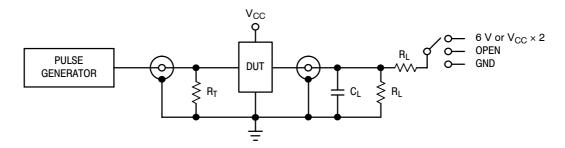


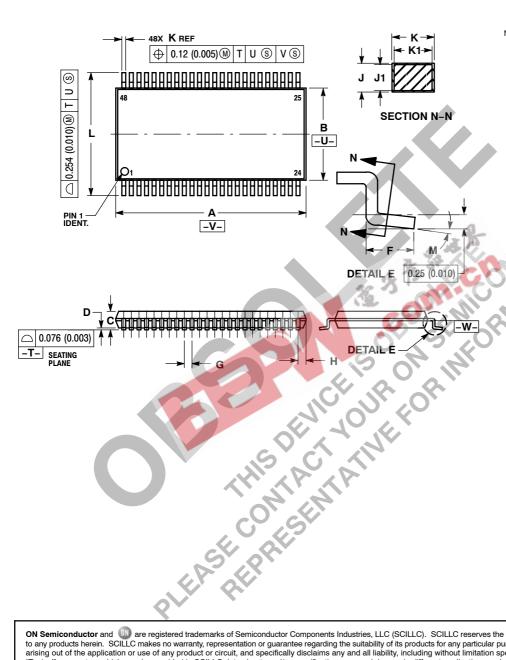
Figure 7. Test Circuit

#### **Table 5. TEST CIRCUIT**

Table 5. TEST CIRCUIT					
TEST	SWITCH				
t <sub>PLH</sub> , t <sub>PHL</sub>	Open				
t <sub>PZL</sub> , t <sub>PLZ</sub>	6 V at $V_{CC}$ = 3.3 ± 0.3 V; $V_{CC}$ × 2 at $V_{CC}$ = 2.5 ± 0.2 V; 1.8 ± 0.15 V	OP			
t <sub>PZH</sub> , t <sub>PHZ</sub>	GND				
$C_L$ = 50 pF or equivalent (Includes jig and probe capacitance) $R_L$ = 500 $\Omega$ or equivalent $R_T$ = $Z_{OUT}$ of pulse generator (typically 50 $\Omega$ )					

#### PACKAGE DIMENSIONS

#### **TSSOP DT SUFFIX** CASE 1201-01 **ISSUE A**



#### NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982
- Y14.5M, 1982.
  CONTROLLING DIMENSION: MILLIMETER.
  DIMENSIONS A AND B DO NOT INCLUDE
  MOLD FLASH, PROTRUSIONS OR GATE
  BURRS. MOLD FLASH OR GATE BURRS
  SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
  DIMENSION K DOES NOT INCLUDE DAMBAR
  PROTRUSION. ALLOWABLE DAMBAR
  PROTRUSION SHALL BE O.08 (0.003) TOTAL IN
  EXCESS OF THE K DIMENSION AT MAXIMUM
  MATERIAL CONDITION.
  TERMINAL INIMPERS ARE SHOWN FOR
- TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
  DIMENSIONS A AND B ARE TO BE
- DETERMINED AT DATUM PLANE -W-.

	MILLIMETERS		INCHES				
DIM	MIN	MAX	MIN	MAX			
Α	12.40	12.60	0.488	0.496			
В	6.00	6.20	0.236	0.244			
C		1.10		0.043			
D	0.05	0.15	0.002	0.006			
_F_	0.50	0.75	0.020	0.030			
G	0.50 BSC		0.0197 BSC				
H	0.37		0.015				
J	0.09	0.20	0.004	0.008			
J1	0.09	0.16	0.004	0.006			
K	0.17	0.27	0.007	0.011			
K1	0.17	0.23	0.007	0.009			
Ĺ	7.95	8.25	0.313	0.325			
M	0 °	8°	0 °	8°			

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